

6MBI150VX-120-50

IGBT Modules

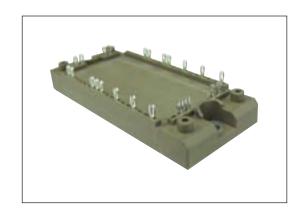
IGBT MODULE (V series) 1200V / 150A / 6 in one package

■ Features

Compact Package P.C.Board Mount Low Vce (sat)

Applications

Inverter for Motor Drive
AC and DC Servo Drive Amplifier
Uninterruptible Power Supply
Industrial machines, such as welding machines



■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items		Symbols	Conditions		Maximum ratings	Units	
	Collector-Emitter voltage		Vces			1200	V
	Gate-Emitter v	ate-Emitter voltage				±20	V
rter	Collector current		Ic	Continuous	Tc=80°C	150	
nvert			Icp	1ms	Tc=80°C	300	٨
Ē			-lc			150	Α
			-lc pulse	1ms		300	
	Collector power dissipation		Pc	1 device		770	W
Junction temperature		Tj			175		
Operating junciton temperature (under switching conditions)			Tjop			150	°C
Case temperature		Tc	125				
Storage temperature		Tstg	-40 to +125				
Isc	lation voltage	between terminal and copper base (*1) between thermistor and others (*2)	Viso	AC : 1min.		2500	VAC
Sc	rew torque	Mounting (*3)	-	M5		3.5	N m

Note *1: All terminals should be connected together during the test.

Note *2: Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

Note *3: Recommendable value : 2.5-3.5 Nm (M5)

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● Electrical characteristics (at Tj= 25°C unless otherwise specified)

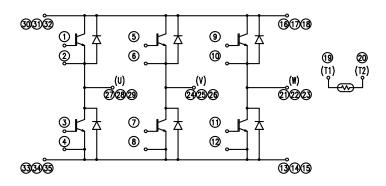
Items		Symbols	Conditions		Characteristics			Units
		Symbols			min.	typ.	max.	Ullits
Inverter	Zero gate voltage collector current	Ices	V _{GE} = 0V, V _{CE} = 1200V		-	-	1.0	mA
	Gate-Emitter leakage current	Iges	$V_{GE} = 0V$, $V_{GE} = \pm 20V$		-	-	200	nA
	Gate-Emitter threshold voltage	V _{GE (th)}	V _{CE} = 20V, I _C = 150mA		6.0	6.5	7.0	V
		V _{CE (sat)} (terminal)	V _{GE} = 15V I _C = 150A	Tj=25°C	-	2.50	2.95	V
	Collector-Emitter saturation voltage			Tj=125°C	-	2.80	-	
				Tj=150°C	-	2.85	-	
		V _{CE (sat)} (chip)	V _{GE} = 15V I _C = 150A	Tj=25°C	-	1.75	2.20	
				Tj=125°C	-	2.05	-	
				Tj=150°C	-	2.10	-	
	Input capacitance	Cies	V _{CE} = 10V, V _{GE} = 0V, f = 1MHz		-	13.7	-	nF
	Turn-on time	ton	V _{cc} = 600V I _c = 150A V _{GE} = +15 / -15V R _G = 1.1Ω		-	0.39	1.20	μs
		tr			-	0.09	0.60	
		tr (i)			-	0.03	-	
	Town off the c	toff			-	0.53	1.00	
	Turn-off time	tf			-	0.06	0.30	
		V _F (terminal)	I _F = 150A	Tj=25°C	-	2.45	2.90	V
	Forward on voltage			Tj=125°C	-	2.60	-	
				Tj=150°C	-	2.55	-	
		V _F (chip)	I _F = 150A	Tj=25°C	-	1.70	2.15	
				Tj=125°C	-	1.85	-	
				Tj=150°C	-	1.80	-	
	Reverse recovery time	trr	I _F = ±20		-	-	0.1	μs
ţo	Parietenas	R	T = 25°C		-	5000	-	Ω
Thermistor	Resistance		T = 100°C		465	495	520	
The	B value	В	T = 25 / 50°C		3305	3375	3450	K

● Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
items		Conditions	min.	typ.	max.	Ullits
Thermal registeres (4 device)	Rth(j-c)	Inverter IGBT	-	-	0.195	°C/W
Thermal resistance (1device)		Inverter FWD	-	-	0.34	
Contact thermal resistance (1device) (*4)	Rth(c-f)	with Thermal Compound	-	0.05	-	

Note *4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

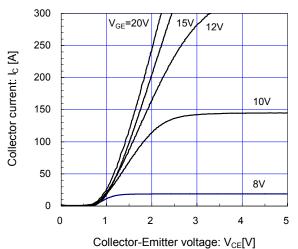
■ Equivalent Circuit Schematic



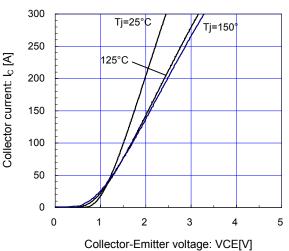
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■ Characteristics (Representative)

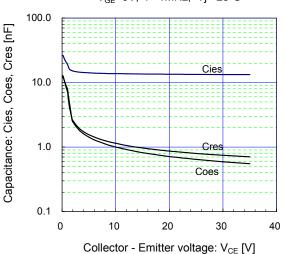
 $[\ \, Inverter \]$ Collector current vs. Collector-Emitter voltage (typ.) $Tj{=}\ 25^{\circ}C\ /\ chip$



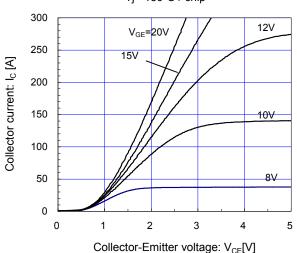
 $[\ Inverter\]$ Collector current vs. Collector-Emitter voltage (typ.) $V_{GE} {=} 15V\ /\ chip$



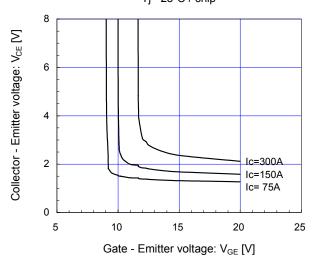
 $\label{eq:continuous} \begin{tabular}{ll} [Inverter] \\ Capacitance vs. Collector-Emitter voltage (typ.) \\ V_{GE} = 0V, \ f = 1MHz, \ Tj = 25^{\circ}C \end{tabular}$



[Inverter]
Collector current vs. Collector-Emitter voltage (typ.)
Tj= 150°C / chip



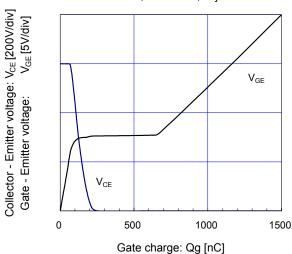
 $[Inverter\] \\ Collector-Emitter\ voltage\ vs.\ Gate-Emitter\ voltage\ (typ.) \\ Tj=25^{\circ}C\ /\ chip$



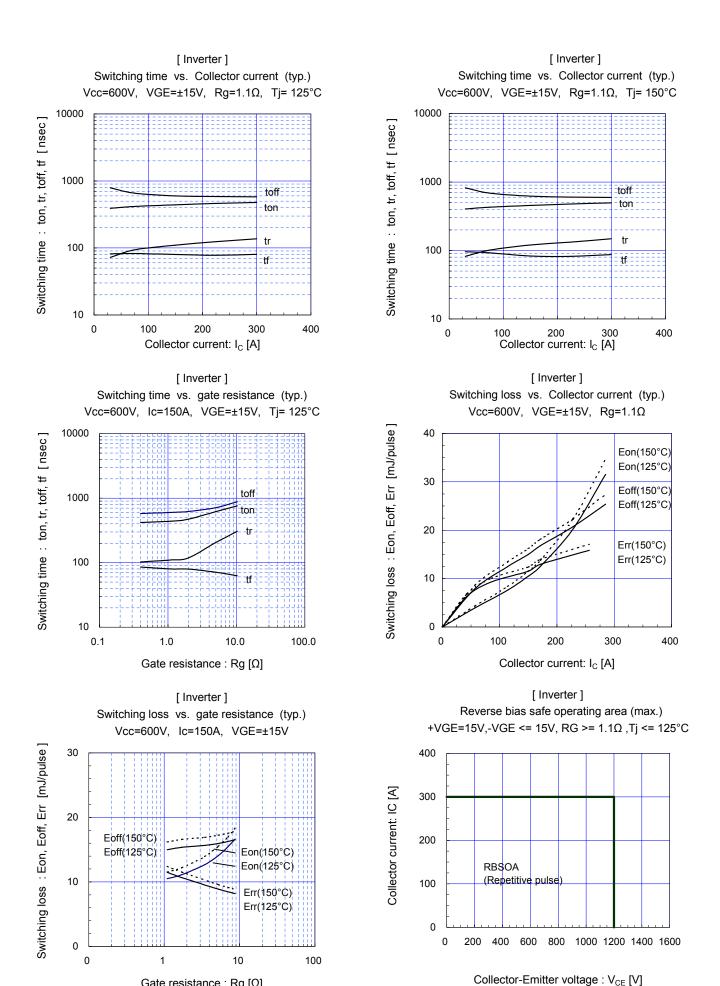
[Inverter]

Dynamic gate charge (typ.)

Vcc=600V, Ic=150A, Tj= 25°C

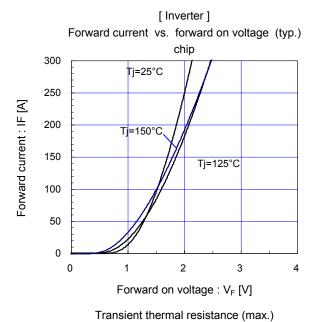


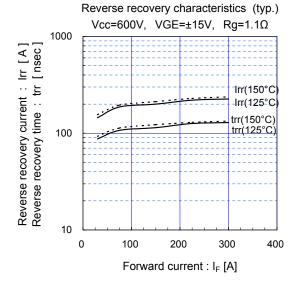
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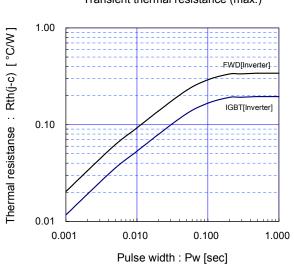
Gate resistance : Rg $[\Omega]$

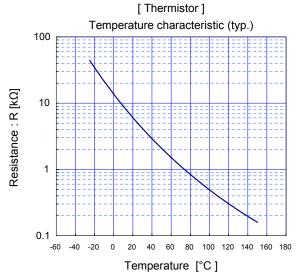
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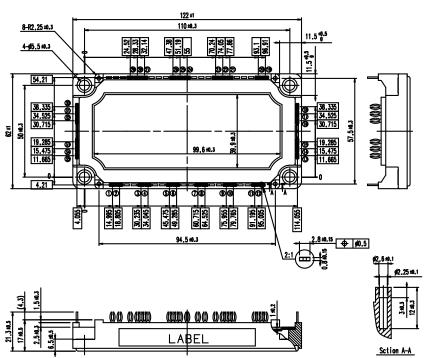


[Inverter]









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